

Rectifier Diode



DS5979 - 1 January 2011 (LN28000)

FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

V _{RRM}	4500V
I _{F(AV)}	2000A
I _{FSM}	31000A

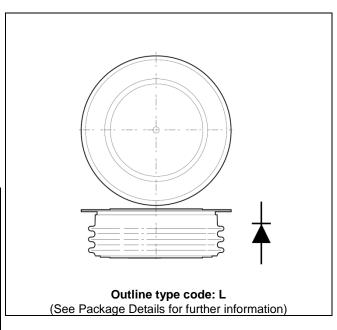


Fig. 1 Package outline

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DRD2000L45 DRD2000L44 DRD2000L42 DRD2000L40	4500 4400 4200 4000	V _{RSM} = V _{RRM} +100V

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD2000L42 for a 4200V device



CURRENT RATINGS

T_{case} = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units		
Double Si	Double Side Cooled					
I _{F(AV)}	Mean forward current	Half wave resistive load	2590	А		
I _{F(RMS)}	RMS value	-	4068	А		
lF	Continuous (direct) on-state current	-	3727	А		
Single Sid	Single Side Cooled (Anode side)					
I _{F(AV)}	Mean forward current	Half wave resistive load	1940	Α		
I _{F(RMS)}	RMS value	-	3047	А		
I _F	Continuous (direct) on-state current	-	2656	А		

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
I _{F(AV)}	Mean forward current	Half wave resistive load	2000	А			
I _{F(RMS)}	RMS value	-	3140	А			
l _F	Continuous (direct) on-state current	-	2800	А			
Single Side Cooled (Anode side)							
I _{F(AV)}	Mean forward current	Half wave resistive load	1284	А			
I _{F(RMS)}	RMS value	-	2017	А			
IF	Continuous (direct) on-state current	-	1715	A			



SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	24.8	kA
l ² t	I ² t for fusing	V_{R} = 50% V_{RRM} - 1⁄4 sine	3.075	MA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 150^{\circ}C$	31.0	kA
l ² t	I ² t for fusing	$V_R = 0$	4.8	MA ² s

THERMAL AND MECHANICAL RATINGS

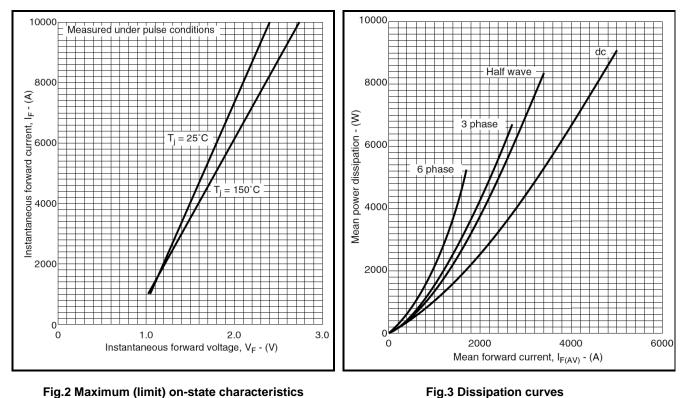
Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.013	°C/W
		Single side cooled	Anode DC	-	0.025	°C/W
			Cathode DC	-	0.027	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 45kN	Double side	-	0.003	°C/W
		(with mounting compound)	Single side	-	0.006	°C/W
T_{vj}	Virtual junction temperature	On-state (conducting)		-	160	°C
		Reverse (blocking)		-	150	°C
T _{stg}	Storage temperature range			-55	175	°C
Fm	Clamping force			40	48	kN

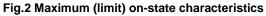


CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V_{FM}	Forward voltage	At 3000A peak, T _{case} = 25°C	-	1.45	V
I _{RM}	Peak reverse current	At V _{RRM,} T _{case} = 150°C	-	150	mA
Qs	Total stored charge	I _F = 1500A, dI _{RR} /dt =25A/µs	-	6000	μC
Irr	Peak reverse recovery current	$T_{case} = 25^{\circ}C, V_{R} = 100V$	-	500	А
V _{TO}	Threshold voltage	At T _{vj} = 150°C	-	0.84	V
٢ _T	Slope resistance	At T _{vj} = 150°C	-	0.19	mΩ

CURVES



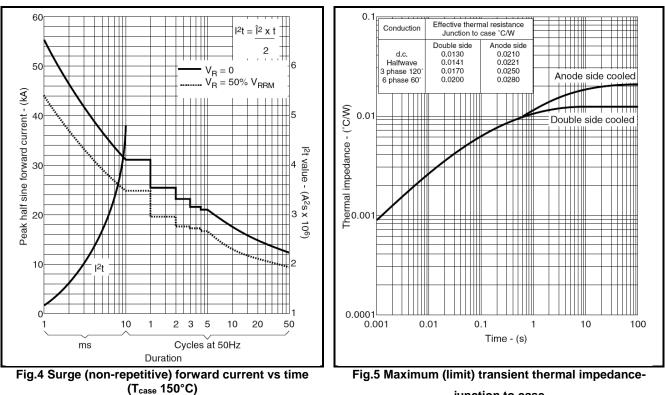


V_{TM} EQUATION

 $V_{TM} = A + Bln (I_T) + C.I_T + D.\sqrt{I_T}$

Where A = -0.36984B = 0.292197C = 0.000354D = -0.03111 these values are valid for $T_j = 150^{\circ}C$ for I_F 500A to 10000A



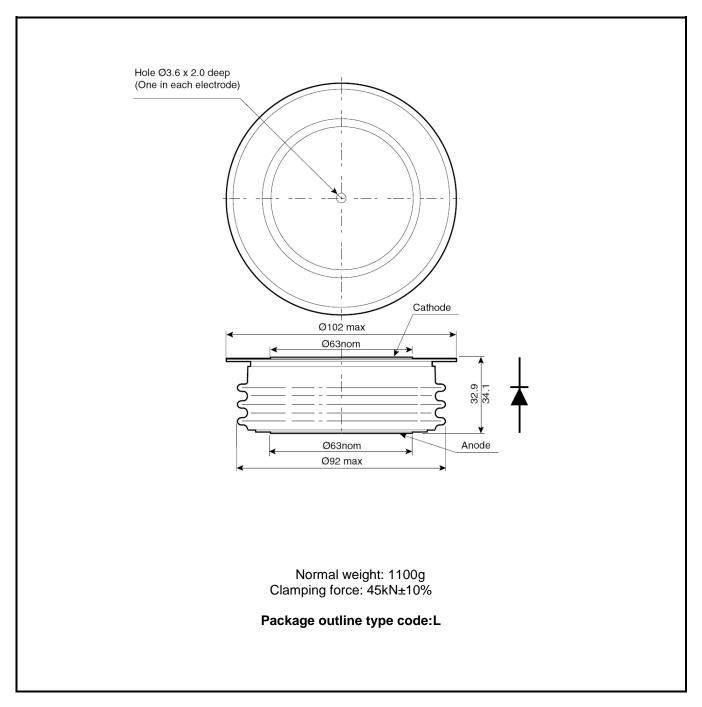


junction to case



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.



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